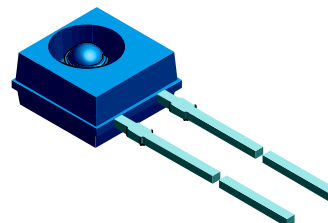


Silicon NPN Phototransistor

Description

TEKT5400S is a high sensitive silicon NPN epitaxial planar phototransistor in a flat side view plastic package. A small recessed lens provides a high sensitivity in a low profile case.

The molded package itself is an IR filter, spectrum matched to IR emitters ($\lambda_p > 850\text{nm}$ or 950 nm).



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Features

- High photo sensitivity
- Daylight filter
- Molded package with side view lens
- Angle of half sensitivity $\phi = \pm 37^\circ$
- Matched with IR-Emitter TSKS5400S

Applications

- Detector in electronic control and drive circuits

Order Instruction

Ordering Code	Remarks
TEKT5400S	2000 pcs in Plastic Bags
TEKT5400S-ASZ	2.54 mm Pin distance (lead to lead), height of taping 16 mm

Absolute Maximum Ratings

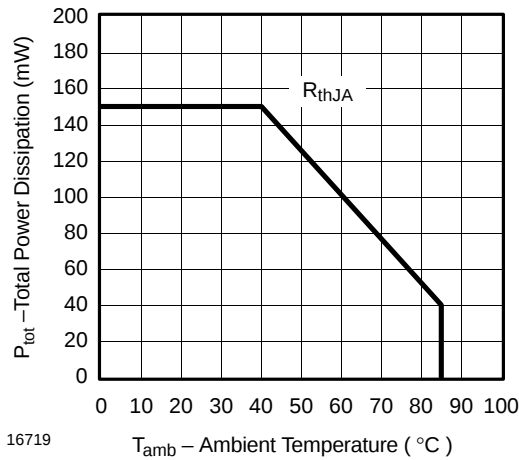
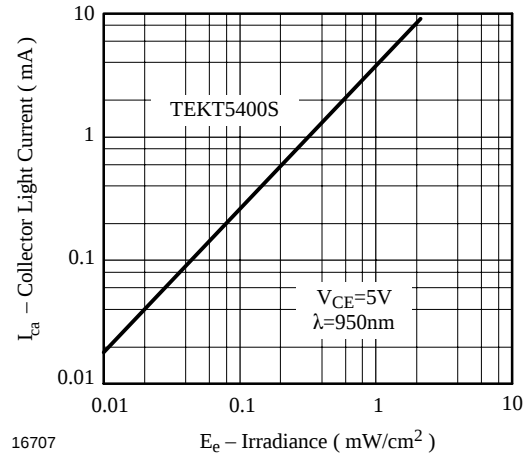
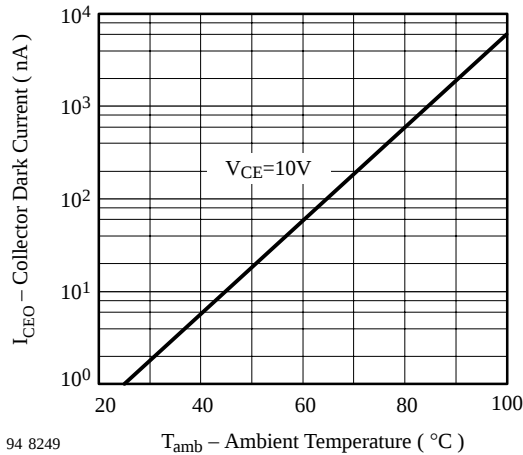
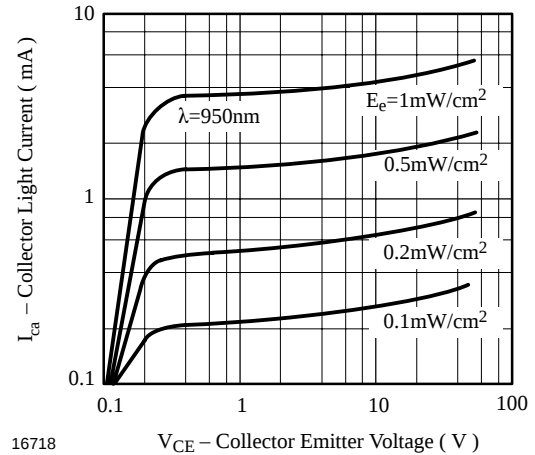
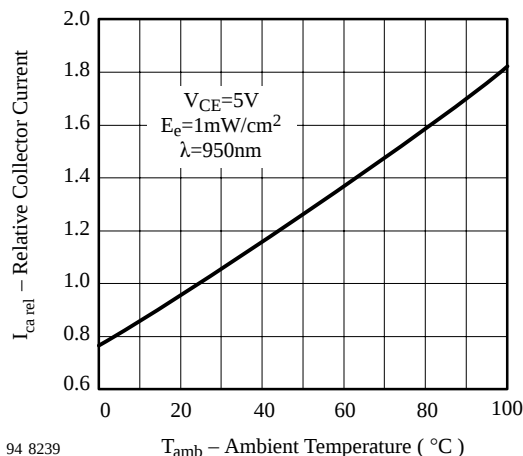
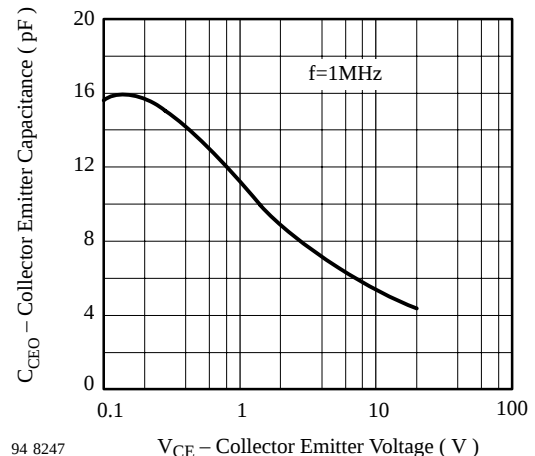
 $T_{amb} = 25^\circ\text{C}$

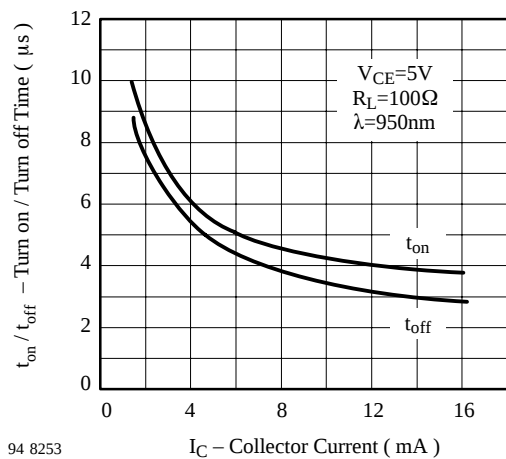
Parameter	Test Conditions	Symbol	Value	Unit
Collector Emitter Voltage		V_{CEO}	70	V
Emitter Collector Voltage		V_{ECO}	7	V
Collector Current		I_C	100	mA
Peak Collector Current	$t_p/T = 0.5$, $t_p \leq 10\text{ ms}$	I_{CM}	200	mA
Total Power Dissipation	$T_{amb} \leq 40^\circ\text{C}$	P_{tot}	150	mW
Junction Temperature		T_j	100	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	$-40...+100$	$^\circ\text{C}$
Operating Temperature		T_{amb}	$-40...+85$	$^\circ\text{C}$
Soldering Temperature	$t \leq 5\text{ s}$	T_{sd}	260	$^\circ\text{C}$
Thermal Resistance Junction/Ambient		R_{thJA}	400	K/W

Basic Characteristics

$T_{amb} = 25^{\circ}\text{C}$

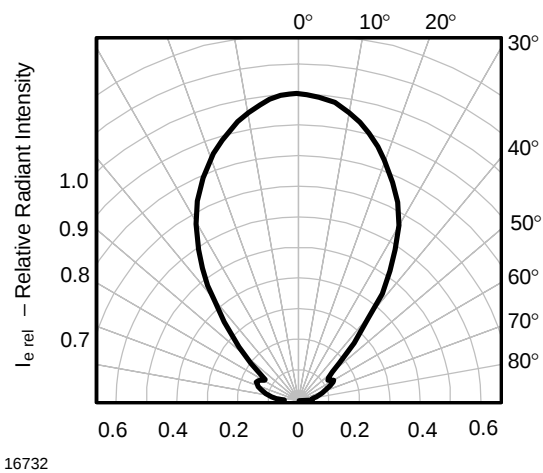
Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector Emitter Voltage	$I_C = 1\text{ mA}$	V_{CEO}	70			V
Emitter Collector Voltage	$I_E = 100\text{ }\mu\text{A}$	V_{ECO}	7			V
Collector Dark Current	$V_{CE} = 20\text{ V}$, $E = 0$	I_{CEO}		1	100	nA
Collector Emitter Capacitance	$V_{CE} = 5\text{ V}$, $f = 1\text{ MHz}$, $E = 0$	C_{CEO}		6		pF
Collector Light Current	$E_{CE} = 5\text{ V}$, $E_e = 1\text{ mW/cm}^2$, $\lambda_p = 950\text{ nm}$	I_{ca}	2	4		mA
Angle of Half Sensitivity		ϕ		± 37		deg
Wavelength of Peak Sensitivity		λ_p		920		nm
Range of Spectral Bandwidth		$\lambda_{0.5}$		850...980		nm
Collector Emitter Saturation Voltage	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$, $I_C = 0.1\text{ mA}$	V_{CEsat}			0.3	V
Turn-On Time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{on}		6		μs
Turn-Off Time	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{off}		5		μs
Cut-Off Frequency	$V_S = 5\text{ V}$, $I_C = 5\text{ mA}$, $R_L = 100\text{ }\Omega$	f_c		110		kHz

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

Figure 1. Total Power Dissipation vs. Ambient Temperature

Figure 4. Relative Radiant Intensity vs. Angular Displacement

Figure 2. Collector Dark Current vs. Ambient Temperature

Figure 5. Collector Light Current vs. Collector Emitter Voltage

Figure 3. Relative Collector Current vs. Ambient Temperature

Figure 6. Collector Emitter Capacitance vs. Collector Emitter Voltage



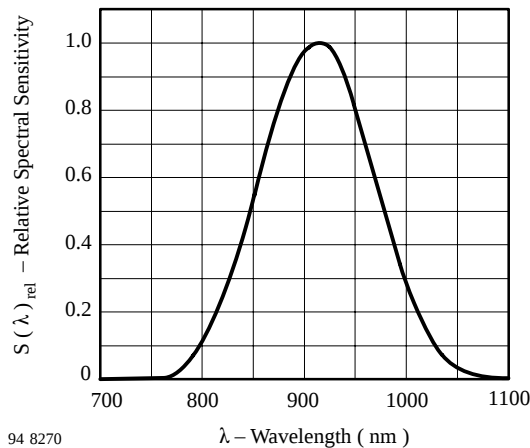
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Figure 7. Turn On/Turn Off Time vs. Collector Current



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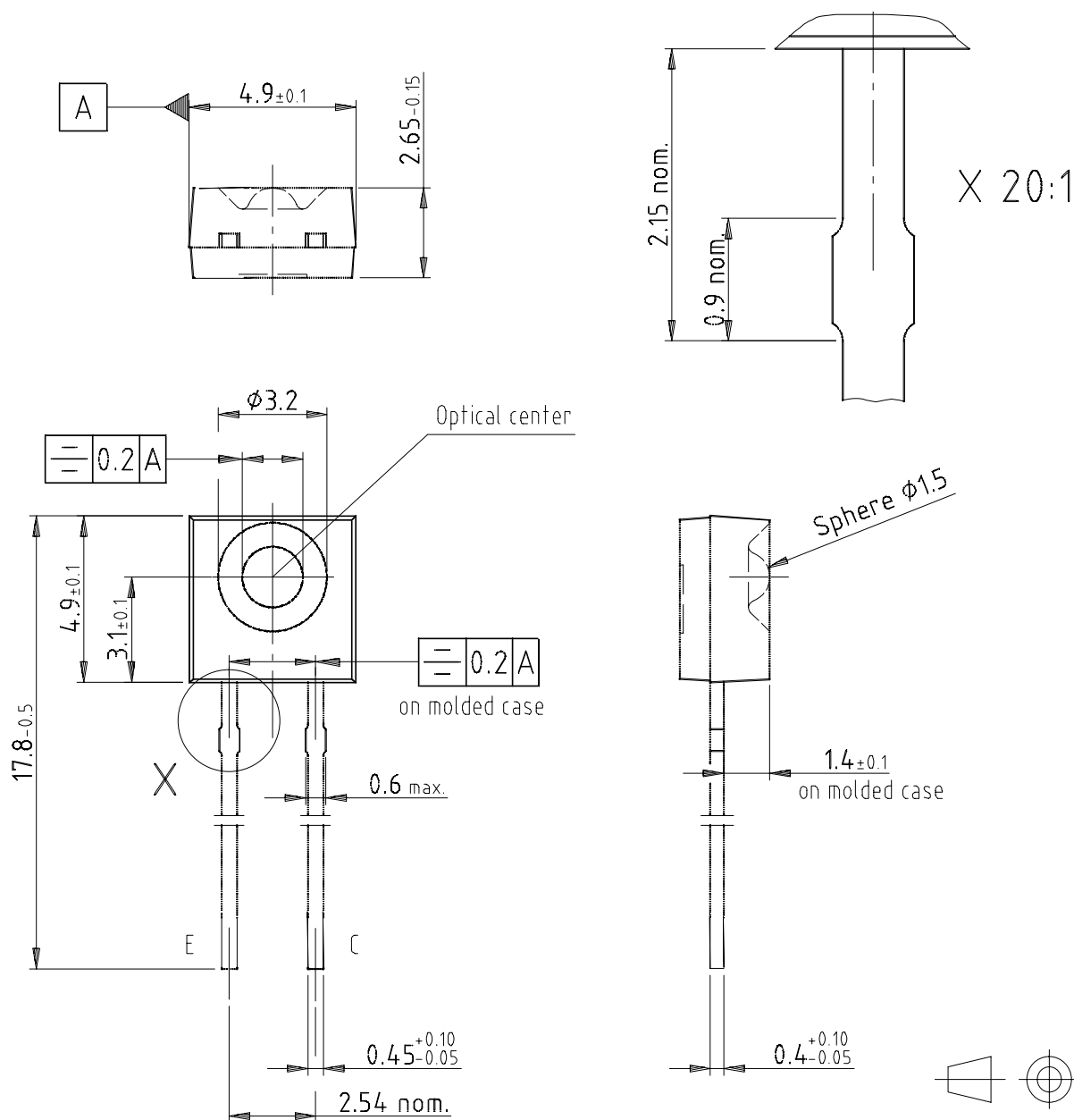
Figure 9. Relative Radiant Intensity vs. Angular Displacement



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Figure 8. Relative Spectral Sensitivity vs. Wavelength

Dimensions in mm

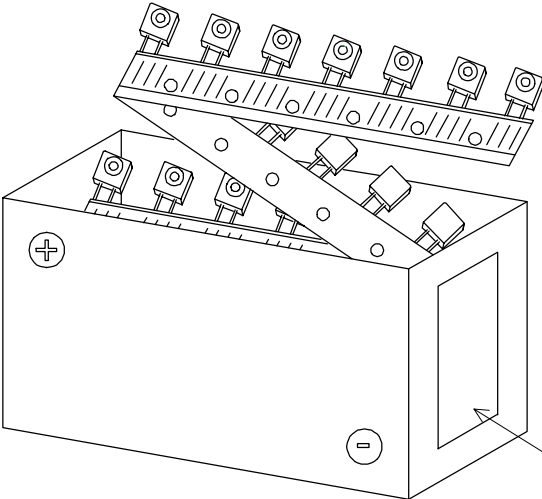


Drawing-No.: 6.544-5347.01-4
Issue: 1; 27.02

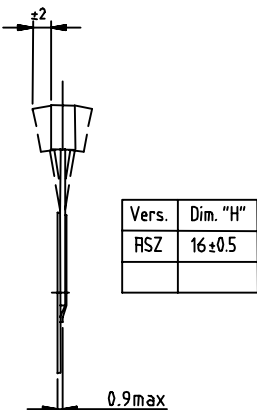
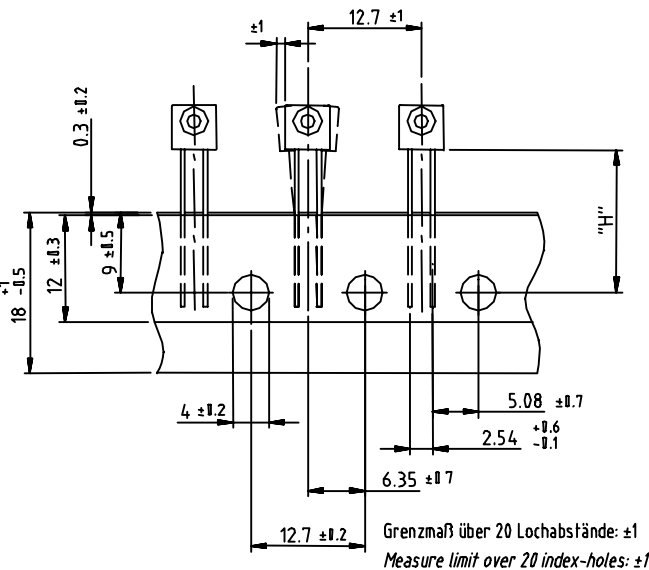
Lead spacing is measured where the leads emerged from the package

16706

Tape and Ammopack Standards



Kennzeichnung: Barcode-Etikett siehe 5.6.4
Labeling: Barcode-label see 5.6.4



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Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

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С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331